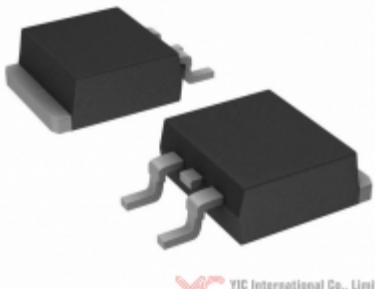









	<h2 style="color: red;">IPB45N06S3-16</h2>	
	Hersteller-Teilenummer:	IPB45N06S3-16
	Hersteller / Marke:	International Rectifier (Infineon Technologies)
	Teil der Beschreibung:	MOSFET N-CH 55V 45A TO-263
Datenblätter:	 IPB45N06S3-16.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 6500 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	IPB45N06S3-16
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	MOSFET N-CH 55V 45A TO-263
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	6500 pcs Stock
Serie	OptiMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	PG-TO263-3-2
Verlustleistung (max)	65W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (V _{dss})	55V
Strom - Ununterbrochener Abfluss (I _d) bei 25 °C	45A (Tc)
R _{ds On} (Max) @ I _d , V _{gs}	15.4 mOhm @ 23A, 10V
V _{GS} (th) (Max) @ I _d	4V @ 30μA
Gate Charge (Q _g) (Max) @ V _{gs}	57nC @ 10V
Eingabekapazität (C _{iss}) (Max) @ V _{ds}	2980pF @ 25V
Verpackung	Original-Reel®













































IPB45N06S3-16 ist neu im Original, Suche IPB45N06S3-16 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPB45N06S3-16 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPB45N06S3-16: Info@Y-IC.com

Sie können auch interessiert sein:

 IPB45N04S4L-08 VB IPB45N04S4L-08 VB	 IPB45N06S4L-08 VB IPB45N06S4L-08 VB	 IPB45N06S3L-13 International Rectifier (Infineon Technologies) MOSFET N-CH 55V 45A TO-263	 IPB45N06S409ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 60V 45A TO263-3
 IPB45N06S4-09 INFINEO IPB45N06S4-09 INFINEO	 IPB45N06S409ATMA2 International Rectifier (Infineon Technologies) MOSFET N-CH 60V 45A TO263-3	 IPB35N12S3L26ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CHANNEL_100+	 IPB45N04S4L08ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 40V 45A TO263-3-2

heiße Teile

Mehr

 IPB180N04S4-01	 IPB180N04S4-H0	 IPB180N06S4-H1	D IPB200N15N3	 IPB200N15N3G
 IPB200N15N3S	 IPB200N25N3	D IPB200N25N3G	 IPB22N03S4-15	 IPB22N03S4L-15
 IPB230N06L3G	 IPB25N06S3-22	 IPB25N06S3-25	 IPB25N06S3L-22	 IPB260N06N3
D IPB260N06N3G	 IPB26CN10NG	 IPB26CNE8N	 IPB26CNE8NG	 IPB320N20N3
 IPB320N20N3G	 IPB34CN10NG	 IPB35CN10NG	 IPB35N10S3L-26	 IPB45N04S4L-08
 IPB45N06S3L-13	 IPB45N06S4-09	D IPB45N06S4L-08	 IPB45P03P4L-11	 IPB47N10S-33
 IPB47N10SL-26	D IPB50CN10NG	 IPB50N10S3L	 IPB50N10S3L-16	 IPB50R140
 IPB50R140CP	 IPB50R199CP	 IPB50R250CP	 IPB50R299CP	 IPB530N15N3G
 IPB600N25N3G	 IPB60R099C6	 IPB60R099CPA	D IPB60R125C6	 IPB60R125CP
 IPB60R165CP	 IPB60R190C6	 IPB60R199CP	 IPB60R199CP/6R199P	 IPB60R250CP

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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